

2812

Docket No.: 50090-233

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#10/C
1-16-03

In re Application of

Yukihiro NAGAI, et al.

Serial No.: 09/631,623

Group Art Unit: 2812

Filed: August 04, 2000

Examiner: M. Kirk

For: SEMICONDUCTOR DEVICE HAVING A POTENTIAL FUSE, AND METHOD
OF MANUFACTURING THE SAME

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AMENDMENT

Commissioner for Patents
Washington, DC 20231

Sir:

The following Amendment and Remarks are submitted in response to the Office

Action dated October 4, 2002.

IN THE CLAIMS:

Please amend claims 1, 4 and 7 as follows.

1. (Twice Amended) A semiconductor device comprising:

a semiconductor substrate;

a first portion comprising a plurality of active regions formed in the
semiconductor substrate;

a plurality of isolation regions separating the active regions from each other;

a second [section] portion comprising at least one trench having an interior
surface formed by side surfaces and a bottom surface;